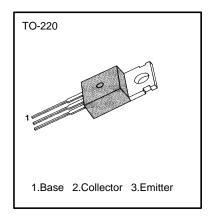
NPN EPITAXIAL SILICON TRANSISTOR

MEDIUM POWER LINEAR SWITCHING APPLICATIONS

• Complementary to TIP30/30A/30B/30C

ABSOLUTE MAXIMUM RATINGS

Characteristic		Symbol	Rating	Unit
Collector Base Voltage	: TIP29	V_{CBO}	40	V
	: TIP29A : TIP29B		60	V
	: TIP29C		80	V
	: TIP29		100	V
Collector Emitter Voltage	: TIP29A	V_{CEO}	40	V
	: TIP29B : TIP29C		60	V
	: 11P29C		80	V
			100	V
Emitter-Base Voltage		V_{EBO}	5	V
Collector Current (DC)		Ic	1	Α
Collector Current (Pulse)		Ic	3	Α
Base Current		I _B	0.4	Α
Collector Dissipation (T _C =25°C)		Pc	30	W
Collector Dissipation (T _A =25°C)		P _C	2	W
Junction Temperature		T_J	150	°C
Storage Temperature		T _{STG}	-65 ~ 150	°C



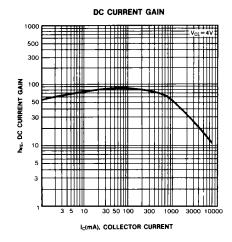
ELECTRICA CHARACTERISTICS (T_C =25°C)

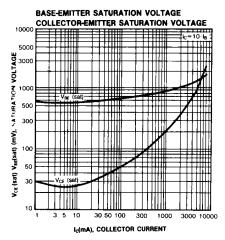
Characteristic	Symbol	Test Conditions	Min	Max	Unit
*Collector Emitter Sustaining Voltage: TIP29	BV _{CEO} (sus)	$I_C = 30 \text{mA}, I_B = 0$	40		V
: TIP29A			60		V
: TIP29B			80		V
: TIP29C			100		V
Collector Cutoff Current : TIP29/29A	I _{CEO}	$V_{CE} = 30V, I_{B} = 0$		0.3	mA
: TIP29B/29C		$V_{CE} = 60V, I_{B} = 0$		0.3	mA
Collector Cutoff Current : TIP29	I _{CES}	$V_{CE} = 40V, V_{EB} = 0$		200	μΑ
: TIP29A		$V_{CE} = 60V, V_{EB} = 0$		200	μΑ
: TIP29B		$V_{CE} = 80V, V_{EB} = 0$		200	μA
: TIP29C		$V_{CE} = 100V, V_{EB} = 0$		200	μΑ
Emitter Cutoff Current	I _{EBO}	$V_{EB} = 5V, I_{C} = 0$		1.0	mA
*DC Current Gain	h _{FE}	$V_{CE} = 4V, I_{C} = 0.2A$	40		
		$V_{CE} = 4V$, $I_C = 1A$	15	75	
*Collector Emitter Saturation Voltage	V _{CE} (sat)	$I_C = 1A$, $I_B = 125mA$		0.7	V
*Base Emitter On Voltage	V _{BE} (on)	$V_{CE} = 4V$, $I_C = 1A$		1.3	V
Current Gain Bandwidth Product	f _T	$V_{CE} = 10V, I_{C} = 200mA$	3.0		MHz
		f = 1MHz			

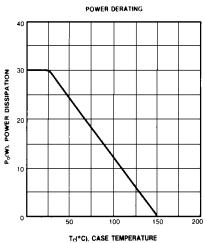
^{*} Pulse Test: PW≤300μs, Duty Cycle≤2%

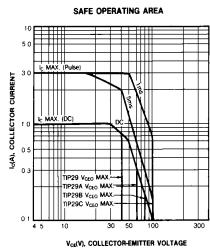


NPN EPITAXIAL SILICON TRANSISTOR











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